NSN 5961-01-037-2189

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-037-2189

Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.340 inches

Overall Diameter:

Between 0.470 inches and 0.500 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage, dc and 7.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current

Power Rating Per Characteristic:

25.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

07187-2501537 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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